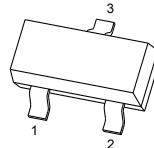
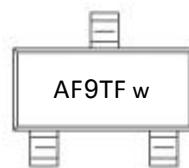


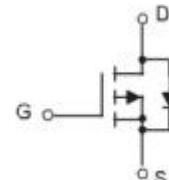
P-Channel 15-V(D-S) MOSFET

V_{(BR)DSS}	R_{D(on)MAX}	I_D
-15V	0.039Ω@-4.5V	-4.3A
	0.052Ω@-2.5V	
	0.063Ω@-1.8V	

SOT-23 / SOT-23-3L

 1.GATE
 2.SOURCE
 3.DRAIN

MARKING


*w: week code

Equivalent Circuit

General FEATURE

- TrenchFET Power MOSFET
- Lead free product is acquired
- Surface mount package

APPLICATION

- Load Switch for Portable Devices
- DC/DC Converter

Maximum ratings (T_a=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	-15	V
Gate-Source Voltage	V _{GS}	±10	
Continuous Drain Current	I _D	-4.3	A
Pulsed Drain Current	I _{DM}	-15	
Continuous Source-Drain Diode Current	I _S	-1.25	
Maximum Power Dissipation	P _D	1	W
Thermal Resistance from Junction to Ambient(t ≤5s)	R _{θJA}	74	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{stg}	-55 ~+150	

MOSFET ELECTRICAL CHARACTERISTICS

T_a = 25 °C unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Static						
Drain-source breakdown voltage	V _{(BR)DSS}	V _{GS} = 0V, I _D = -250µA	-15			V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = -250µA	-0.4	-0.7	-1	
Gate-source leakage	I _{GSS}	V _{DS} = 0V, V _{GS} = ±8V			±100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = -12V, V _{GS} = 0V			-100	nA
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = -4.5V, I _D = -4.3A		0.035	0.039	Ω
		V _{GS} = -2.5V, I _D = -4.1A		0.047	0.052	
		V _{GS} = -1.8V, I _D = -2.0A		0.060	0.063	
Forward transconductance ^a	g _f	V _{DS} = -5V, I _D = -2.0A		5.0	-	S
Dynamic^b						
Input capacitance	C _{iss}	V _{DS} = -4V, V _{GS} = 0V, F = 1.0MHz		740		pF
Output capacitance	C _{oss}			290		
Reverse transfer capacitance	C _{rss}			190		
Total gate charge	Q _g	V _{DS} = -4V, I _D = -4.1A, V _{GS} = -4.5V		7.8		nC
Gate-source charge	Q _{gs}			1.2		
Gate-drain charge	Q _{gd}			1.6		
Gate resistance	R _g	f = 1MHz	1.9		19	Ω
Turn-on delay time	t _{d(on)}	V _{DD} = -4V, I _D = -3.3A, R _L = -1.2Ω, V _{GEN} = -4.5V, R _g = 1Ω		12.0		ns
Rise time	t _r			35.0		
Turn-off delay time	t _{d(off)}			30.0		
Fall time	t _f			10.0		
Drain-source body diode characteristics						
Continuous source-drain diode current	I _s	T _C = 25°C			-1.6	A
Body diode voltage	V _{SD}	I _s = -1.6A		-0.8	-1.2	V

Notes :

a.Pulse Test : Pulse Width < 300µs, Duty Cycle ≤ 2%.

b.Guaranteed by design, not subject to production testing.

Typical Electrical and Thermal Characteristics

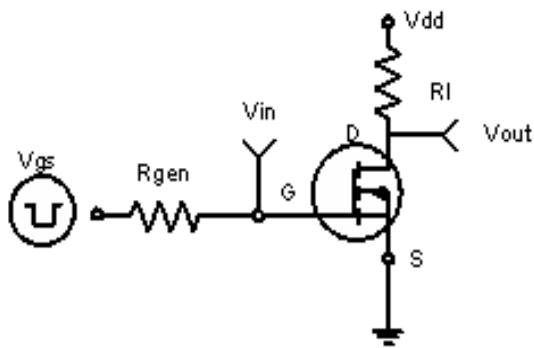


Figure 1:Switching Test Circuit

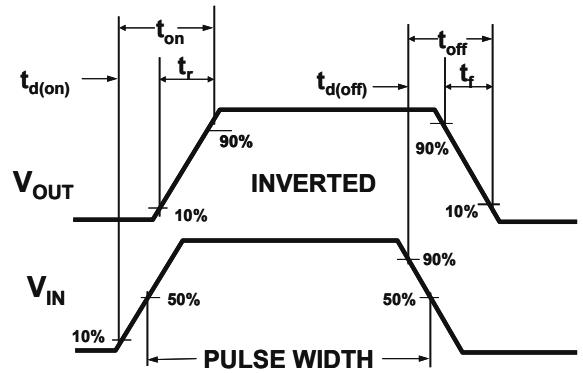


Figure 2:Switching Waveforms

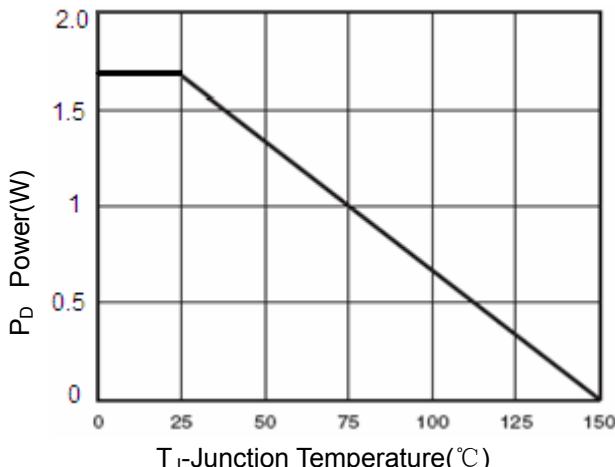


Figure 3 Power Dissipation

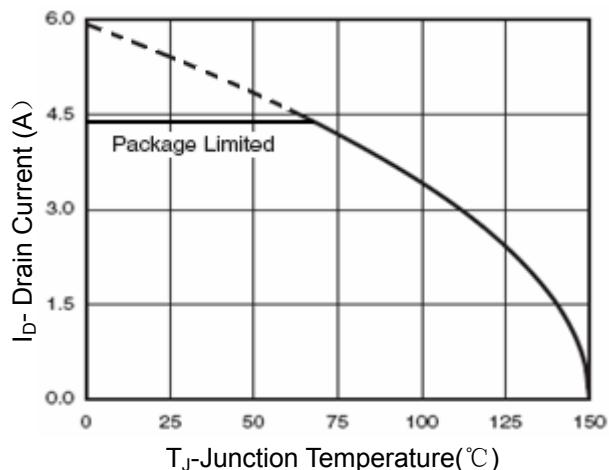


Figure 4 Drain Current

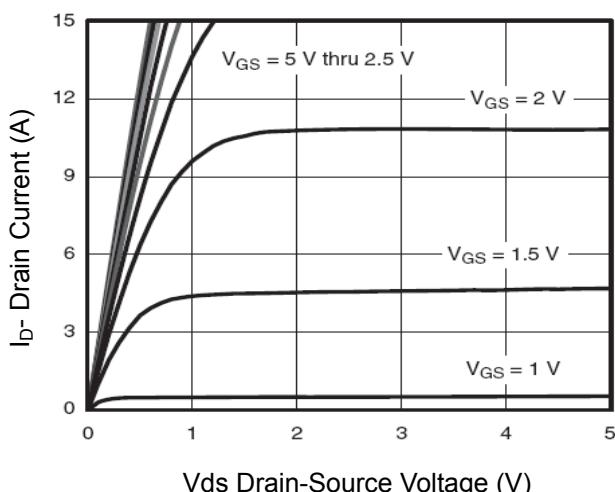


Figure 5 Output Characteristics

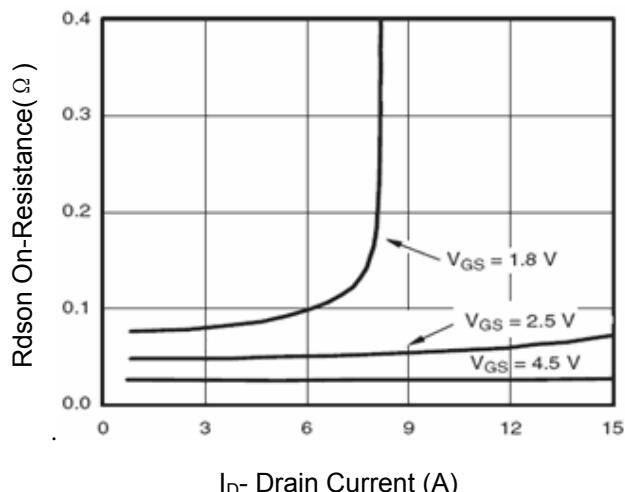


Figure 6 Drain-Source On-Resistance

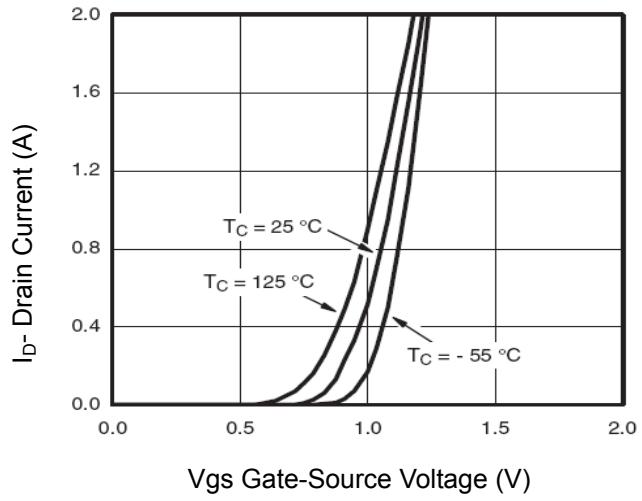


Figure 7 Transfer Characteristics

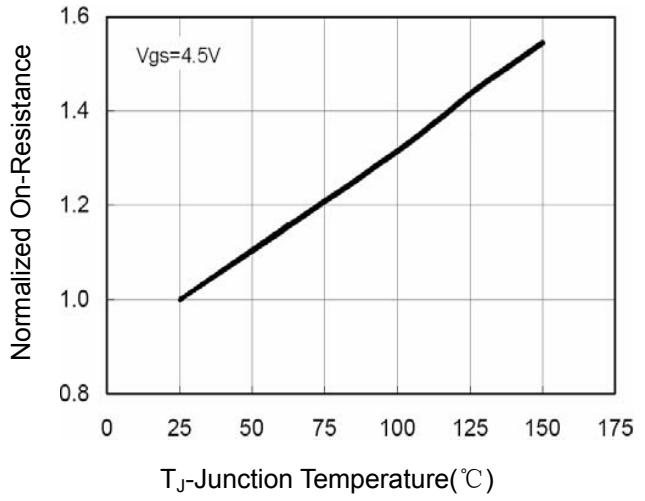


Figure 8 Drain-Source On-Resistance

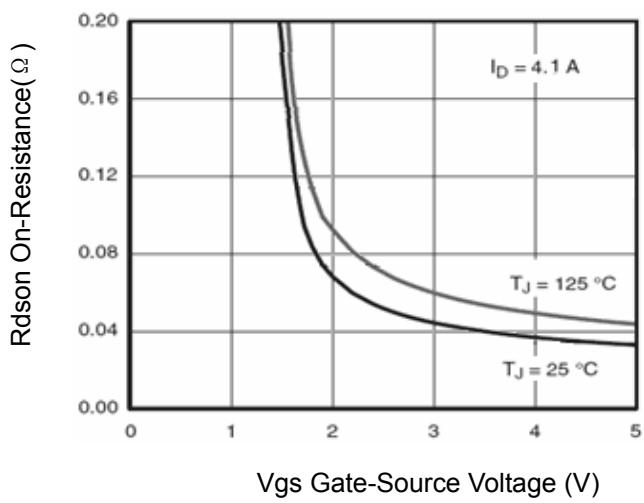


Figure 9 $R_{DS(on)}$ vs V_{GS}

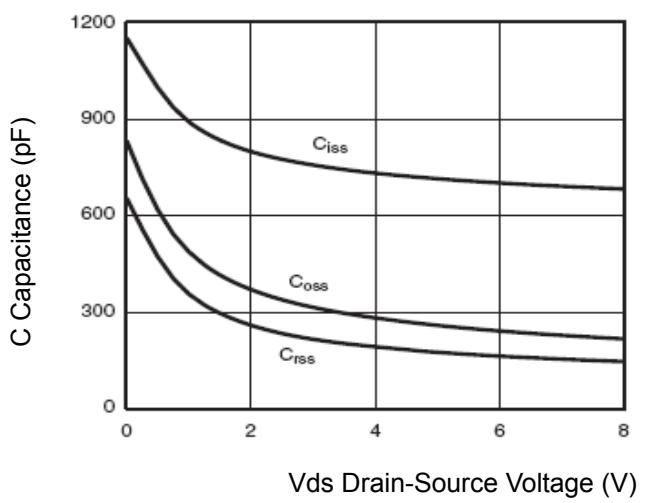


Figure 10 Capacitance vs V_{DS}

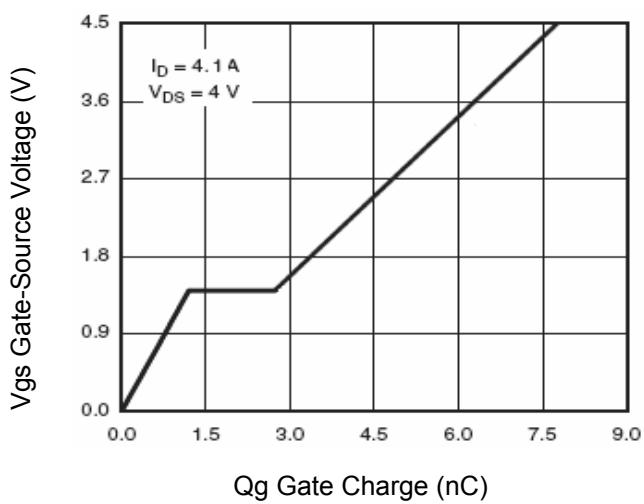


Figure 11 Gate Charge

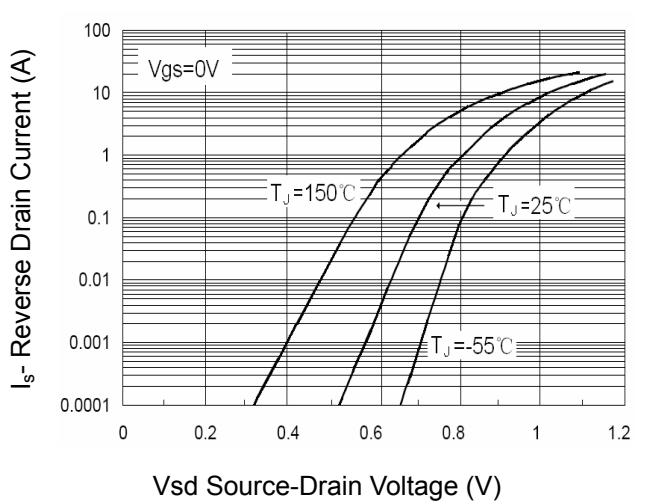


Figure 12 Source- Drain Diode Forward

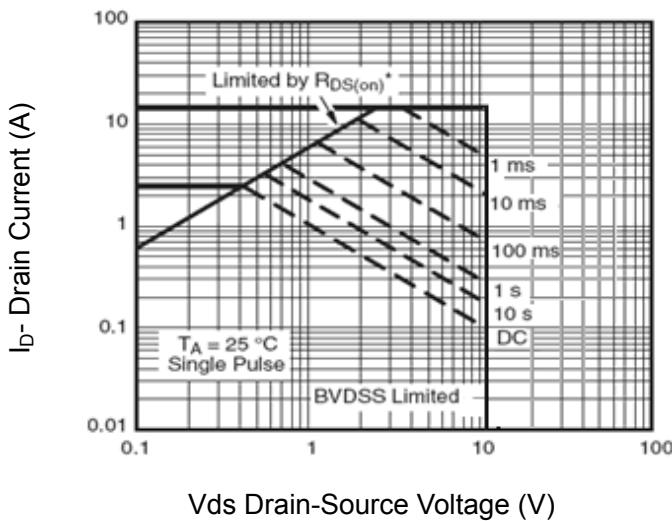


Figure 13 Safe Operation Area

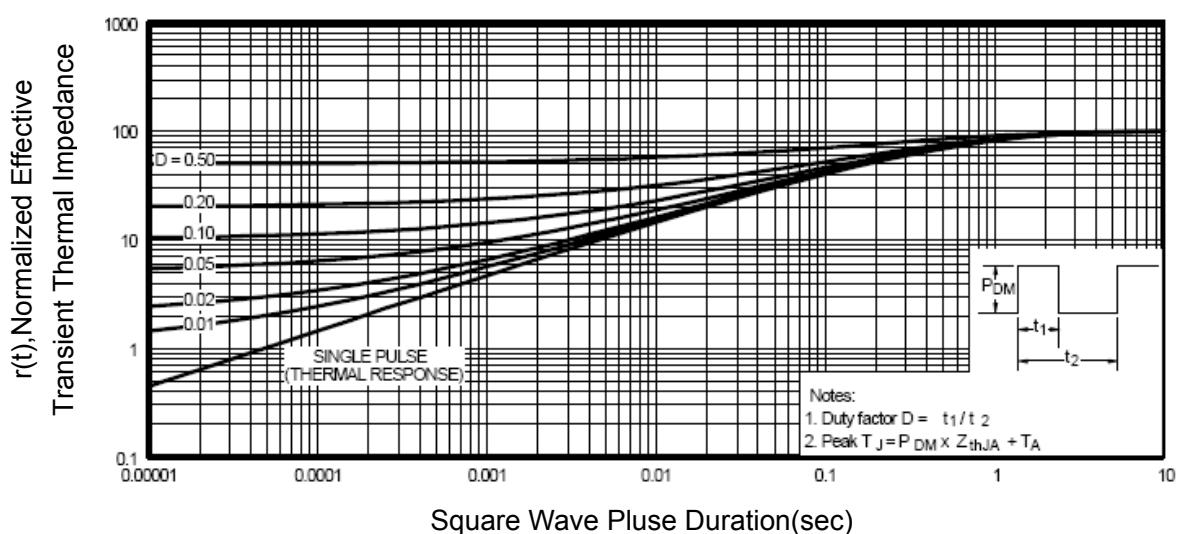
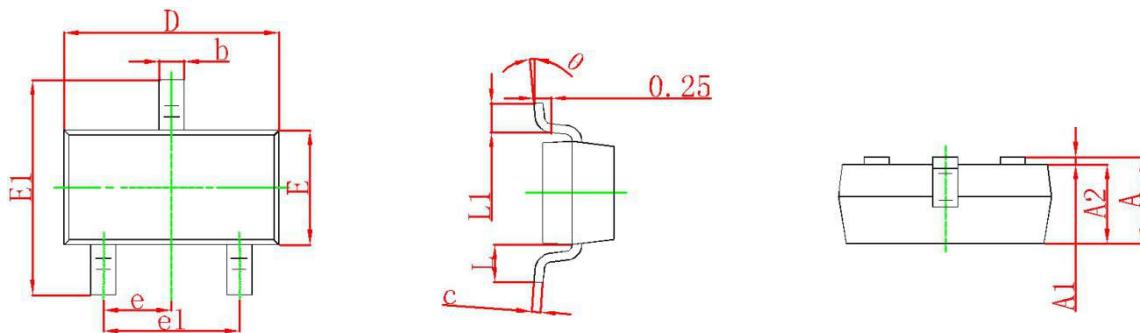


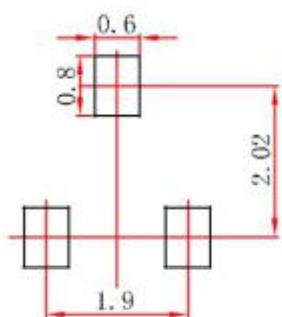
Figure 14 Normalized Maximum Transient Thermal Impedance

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

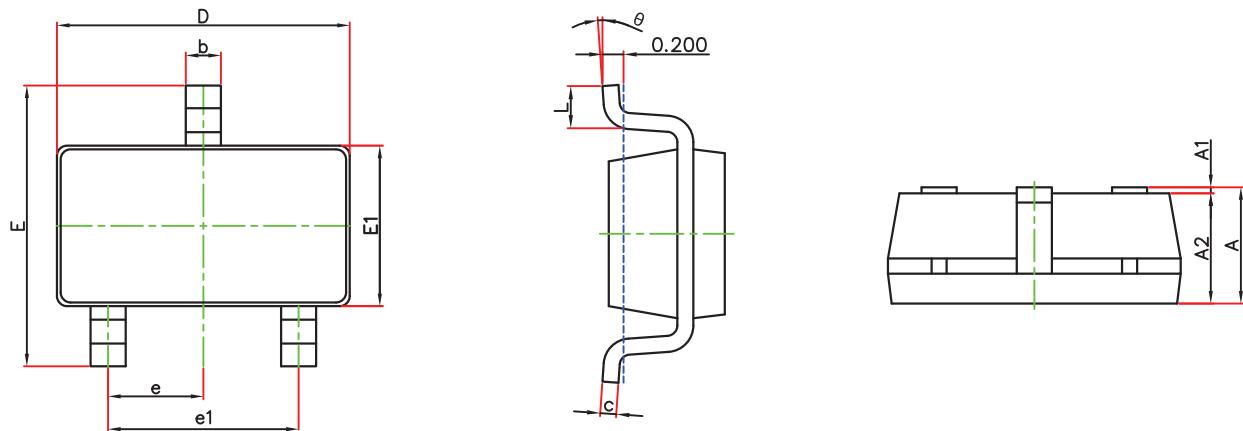
SOT-23 Suggested Pad Layout



Note:

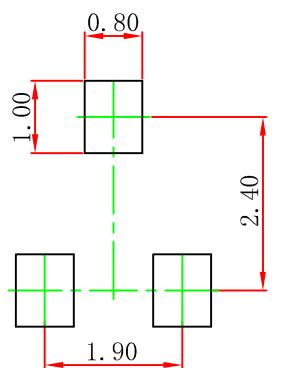
1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.

SOT-23-3L Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
e	0.950(BSC)		0.037(BSC)	
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

SOT-23-3L Suggested Pad Layout



Note:
 1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.